## NSN 5961-01-301-8253

**Demilitarization:** 

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Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-301-8253 **Inclosure Material:** Glass **Overall Length:** 0.170 inches **Terminal Length:** 1.000 inches **Overall Diameter:** 0.090 inches **End Application:** Alq-135b countermeasure **Mounting Method: Terminal Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 500.0 reverse voltage, peak and 1.8 forward voltage, dc **Current Rating Per Characteristic:** 10.00 microamperes forward current, average peak **Power Rating Per Characteristic:** 3.0 watts small-signal input power, common-collector absolute **Maximum Operating Tempurature Per Measurement Point:** 150.0 degrees celsius junction **Special Features:** Fast recovery **Test Data Document:** 26916-019-005536 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing) **Terminal Type And Quantity:** 2 uninsulated wire lead Shelf Life: N/a **Unit Of Measure:**